Date: February 18, 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

Akira Takahashi Group Art Unit: Unknown

Divisional of Serial No. 10/259,351 Examiner: Unknown

Filed: February 18, 2004

For: SEMICONDUCTOR DEVICE AND METHOD FOR MANUFACTURING SAME

INFORMATION DISCLOSURE STATEMENT
(SUBMISSION WITH CONTINUATION-IN-PART OR
RULE 1.53(b) CONTINUATION OR DIVISIONAL APPLICATION)

U.S. Patent and Trademark Office 2011 South Clark Place Customer Window, **Mail Stop Patent Application** Crystal Plaza Two, Lobby, Room 1B03 Arlington, VA 22202

Sir:

Pursuant to 37 C.F.R. §§ 1.97 and 1.98, Applicant hereby submits an Information Disclosure Statement for consideration by the Examiner.

I. <u>LIST OF PATENTS, PUBLICATIONS OR OTHER INFORMATION</u>

The patents, publications or other information submitted for consideration by the Office are listed on PTO-1449 form(s), attached hereto.

II. REFERENCES PREVIOUSLY CITED OR SUBMITTED

Pursuant to 37 C.F.R. § 1.98(d), consideration of information listed on the PTO-1449 form(s) is requested since any patents, publications or other information which are listed on the PTO-1449 form(s) but for which copies are not enclosed herewith, were previously cited by or submitted to the PTO in one of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. § 120:

U.S. Serial Number

U.S. Filing Date

10/259,351 09/713,025 September 30, 2002 November 16, 2000

III. FEES

This Information Disclosure Statement is being filed concurrent with the filing of a continuation-in-part, continuation or divisional patent application; therefore, no fee is required.

If the Examiner has any questions concerning this IDS or requires a copy of any of the references cited but not provided, he/she is requested to contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the PTO is requested to consider this IDS under the proper rule (with a petition if necessary) and charge the appropriate fee to Deposit Account No. 50-0238.

If necessary, the Commissioner is hereby authorized in this, concurrent, and future replies, to charge payment or credit any overpayment to Deposit Account No. 50-0238 for any additional fee required under 37 C.F.R. §§ 1.16 or 1.17; particularly, extension of time fees.

Respectfully submitted,

VOLENTINE FRANCOS, P.L.L.C.

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Enclosure: Two (2) PTO-1449 Forms

INFORMATION DISCLOSURE CITATION

Docket Number (Optional)	Application Number			
OIP.024D2	NEW			
Applicant(s)				
Applicant(s) Akira Takahashi				
Filing Date	Group Art Unit			

	Ar	(Use several sheets if neces	sary)		Akira Takanashi				
					Filing Date February 1	Group Art Unit Unknown			
				U.S. PAT	ENT DOCUMENTS				
*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE		NAME	CLASS	SUBCLASS		G DATE OPRIATE
	A	5,899,721	5/1999	Gardne	Gardner et al.				
	В	6,245,625	6/2001	Gau				. —	
	С	6,495,889	12/2002	Takaha	Takahashi				
"	D	5,610,092	3/1997 Tasal		Tasaka				
						-			1 1 12
				FOREIG	N PATENT DOCUMEN	īTS			
	REF	DOCUMENT NUMBER	DATE		Japan		SUBCLASS	Translation YES NO	
	E	10-4190	1/06/1998	Japan					
	F	2000-49340	2/18/2000	Japan					
	G	9-45908	2/14/1997 Japan	Japan					
			-	OTHER I	OOCUMENTS (Include	ding Author, Title,	Date, Pertinent Pa	ges, Etc.)	l _
		Tomohisa Mizuno et a Transactions on Electr	l., "Hot-Carrier l on Devices, Vol. (njection Su 38, No. 3, M	ppression Due to the I arch 1991, pages 548	Nitride-Oxide LI -591.	DD Spacer Struc	ture,'' IEE	E
		F.C. Hsu et al., "Struc Letters, Vol. EDL-5, N	ture-Enhanced M o. 3, March 1984	OSFET De , pages 71-7	gradation Due to Hot- 4.	-Electron Injecti	on," IEEE Electi	ron Device	
EXAMINE	R				DATE CONSIDERED		-9 99		

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

INFORMATION DISCLOSURE CITATION

Docket Number (Optional)	Application Number			
OIP.024D	NEW			
Applicant(s) Akira Takahashi				
Filing Date	Group Art Unit			
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				U.S. PAT	ENT DOCUMENTS				
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						ng Author, Title, Da			
		Ahn et al., "Hot-Carrier device letters, Vol. 13, 04	degration of sin 4/1992, pp. 711-	igle-drain P 713.	MOSFET's with differ	ing sidewall spac	er thicknesses	", IEEE ele	ectron
	ı								
EXAMINEI	2			-	DATE CONSIDERED				
EXAMINE	R: Initial i	if citation considered, whether o	or not citation is la	conformanc	e with MPEP Section 600	Praw line throug	h citation if not	in conform	ance and
		considered, whether (" " " TITE THE TANK IN THE	. comormant	EL SCUIDH OUY	, with the thiong	A CHAUDH II HOL	in comorm	ALICE ALLU

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.